

# Spread Spectrum System Frequency Synthesizer

#### **Features**

- Maximized EMI suppression using Cypress's spread spectrum technology
- Intel® CK98 Specification compliant
- 0.5% downspread outputs deliver up to 10 dB lower EMI
- · Four skew-controlled copies of CPU output
- Eight copies of PCI output (synchronous w/CPU output)
- Four copies of 66-MHz fixed frequency 3.3V clock
- Two copies of CPU/2 outputs for synchronous memory reference
- Three copies of 16.67-MHz IOAPIC clock, synchronous to CPU clock
- . One copy of 48-MHz USB output
- Two copies of 14.31818-MHz reference clock
- Programmable to 133- or 100-MHz operation
- Power management control pins for clock stop and shut down
- Available in 56-pin SSOP

### **Key Specifications**

Supply Voltages: ......  $V_{DDQ3} = 3.3V \pm 5\%$   $V_{DDQ2} = 2.5V \pm 5\%$ 

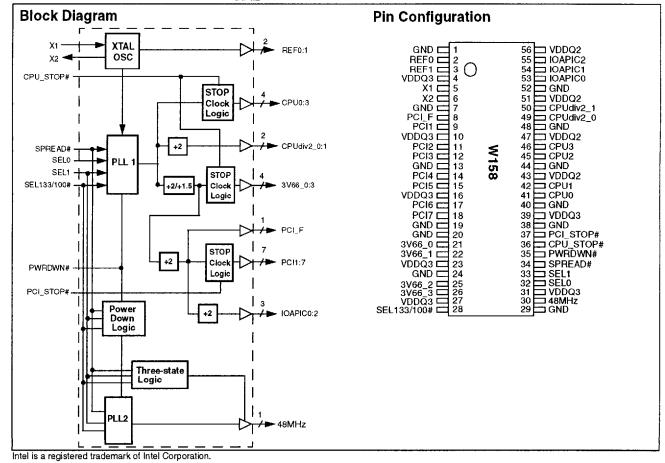
CPU Output Jitter:150 ps
CPUdiv2, IOAPIC Output Jitter:250 ps
48 MHz, 3V66, PCI Output Jitter:500 ps
CPU0:3, CPUdiv2_ 0:1 Output Skew: 175 ps
PCI_F, PCI1:7 Output Skew:500 ps
3V66_0:3, IOAPIC0:2 Output Skew:250 ps
CPU to 3V66 Output Offset: 0.0 to 1.5 ns (CPU leads)
3V66 to PCI Output Offset: 1.5 to 3.0 ns (3V66 leads)
CPU to IOAPIC Output Offset: 1.5 to 4.0 ns (CPU leads)
CPU to PCI Output Offset:1.5 to 4.0 ns (CPU leads)
Logic inputs, except SEL133/100#, have 250-k $\Omega$ pull-up resistors

Table 1. Pin Selectable Frequency<sup>[1]</sup>

SEL133/100#	CPU0:3 (MHz)	PCI
1	133 MHz	33.3 MHz
0	100 MHz	33.3 MHz

#### Note:

1. See Table 2 for complete mode selection details.





#### **Pin Definitions**

Pin Name	Pin No.	Pin Type	Pin Description
CPU0:3	41, 42, 45, 46	0	CPU Clock Outputs 0 through 3: These four CPU clocks run at a frequency set by SEL133/100#. Output voltage swing is set by the voltage applied to VDDQ2.
CPUdiv2_ 0:1	49, 50	0	Synchronous Memory Reference Clock Output 0 through 1: Reference clock for Direct RDRAM clock generators running at 1/2 CPU clock frequency. Output voltage swing is set by the voltage applied to VDDQ2.
PCI1:7	9, 11, 12, 14, 15, 17, 18	0	PCI Clock Outputs 1 through 7: These seven PCI clock outputs run synchronously to the CPU clock. Voltage swing is set by the power connection to VDDQ3. PCI1:7 outputs are stopped when PCI _STOP# is held LOW.
PCI_F	8	0	<b>PCI_F (PCI Free-running):</b> This PCI clock output runs synchronously to the CPU clock. Voltage swing is set by the power connection to VDDQ3. PCI_F is not affected by the state of PCI_STOP#.
REF0:1	2, 3	0	14.318-MHz Reference Clock Output: 3.3V copies of the 14.318-MHz reference clock.
IOAPIC0:2	53, 54, 55	0	I/O APIC Clock Output: Provides 16.67-MHz fixed frequency. The output voltage swing is set by the power connection to VDDQ2.
48MHz	30	0	<b>48-MHz Output:</b> Fixed 48-MHz USB output. Output voltage swing is controlled by voltage applied to VDDQ3.
3V66_0:3	21, 22, 25, 26	0	<b>66-MHz Output 0 through 3:</b> Fixed 66-MHz outputs. Output voltage swing is controlled by voltage applied to VDDQ3.
SEL0:1	32, 33	ı	<b>Mode Select Input 0 through 1:</b> 3.3V LVTTL-compatible input for selecting clock output modes.
SEL133/100#	28	_	Frequency Selection Input: 3.3V LVTTL-compatible input that selects CPU output frequency as shown in Table 1.
X1	5	_	Crystal Connection or External Reference Frequency Input: Connect to either a 14.318-MHz crystal or an external reference signal.
X2	6	0	Crystal Connection: An output connection for an external 14.318-MHz crystal. If using an external reference, this pin must be left unconnected.
SPREAD#	34	Ī	Active LOW Spread Spectrum Enable: 3.3V LVTTL-compatible input that enables spread spectrum mode when held LOW.
PWRDWN#	35	1	<b>Active LOW Power Down Input:</b> 3.3V LVTTL-compatible asynchronous input that requests the device to enter power-down mode.
CPU_STOP#	36	_	Active LOW CPU Clock Stop: 3.3V LVTTL-compatible asynchronous input that stops all CPU and 3V66 clocks when held LOW. CPUdiv2 outputs are unaffected by this input.
PCI_STOP#	37	_	Active LOW PCI Clock Stop: 3.3V LVTTL-compatible asynchronous input that stops all PCI outputs except PCI_F when held LOW.
VDDQ3	4, 10, 16, 23, 27, 31, 39	Р	<b>Power Connection:</b> Power supply for PCI output buffers, 48-MHz USB output buffer, Reference output buffers, 3V66 output buffers, core logic, and PLL circuitry. Connect to 3.3V supply.
VDDQ2	43, 47, 51, 56	Р	<b>Power Connection:</b> Power supply for IOAPIC, CPU, and CPUdiv2 output buffers. Connect to 2.5V supply.
GND	1, 7, 13, 19, 20, 24, 29, 38, 40, 44, 48, 52	G	Ground Connection: Connect all ground pins to the common system ground plane.

#### Overview

The W158 is designed to provide the essential frequency sources to work with advanced multiprocessing Intel architecture platforms. Split voltage supply signaling provides 2.5V and 3.3V clock frequencies operating up to 133 MHz.

From a low-cost 14.31818-MHz reference crystal oscillator, the W158 generates 2.5V clock outputs to support CPUs, core logic chip set, and Direct RDRAM clock generators. It also provides skew-controlled PCI and IOAPIC clocks synchronous to CPU clock, 48-MHz Universal Serial Bus (USB) clock, and replicates the 14.31818-MHz reference clock.

All CPU, PCI, and IOAPIC clocks can be synchronously modulated for spread spectrum operations. Cypress employs proprietary techniques that provide the maximum EMI reduction while minimizing the clock skews that could reduce system timing margins. Spread Spectrum modulation is enabled by the active LOW control signal SPREAD#.

The W158 also includes power management control inputs. By using these inputs, system logic can stop CPU and/or PCI clocks or power down the entire device to conserve system power.



#### **Spread Spectrum Clocking**

The device generates a clock that is frequency modulated in order to increase the bandwidth that it occupies. By increasing the bandwidth of the fundamental and its harmonics, the amplitudes of the radiated electromagnetic emissions are reduced. This effect is depicted in *Figure 1*.

As shown in *Figure 1*, a harmonic of a modulated clock has a much lower amplitude than that of an unmodulated signal. The reduction in amplitude is dependent on the harmonic number and the frequency deviation or spread. The equation for the reduction is:

 $dB = 6.5 + 9*log_{10}(P) + 9*log_{10}(F)$ 

Where P is the percentage of deviation and F is the frequency in MHz where the reduction is measured.

The output clock is modulated with a waveform depicted in *Figure 2*. This waveform, as discussed in "Spread Spectrum Clock Generation for the Reduction of Radiated Emissions" by Bush, Fessler, and Hardin produces the maximum reduction in the amplitude of radiated electromagnetic emissions. The deviation selected for this chip is –0.5% downspread. *Figure 2* details the Cypress spreading pattern. Cypress does offer options with more spread and greater EMI reduction. Contact your local Sales representative for details on these devices.

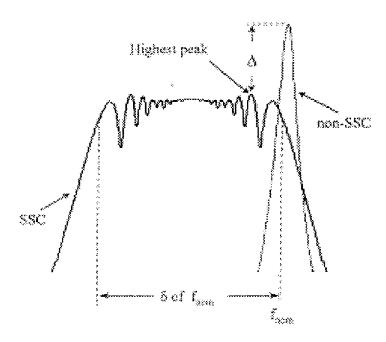


Figure 1. Clock Harmonic with and without SSCG Modulation Frequency Domain Representation

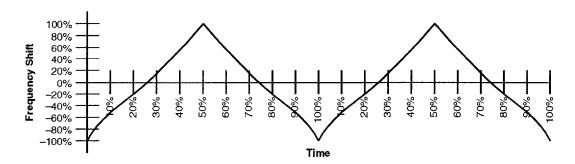


Figure 2. Modulation Waveform Profile



# **Mode Selection Functions**

The W158 supports the following operating modes controlled through the SEL133/100#, SEL0, and SEL1 inputs.

**Table 2. Select Functions** 

SEL133/100#	SEL1	SEL0	Function
0	0	0	All Outputs Three-State
0	0	1	(Reserved)
0	1	0	Active 100-MHz, 48-MHz PLL Inactive
0	1	1	Active 100-MHz, 48-MHz PLL Active
1	0	0	Test Mode
1	0	1	(Reserved)
1	1	0	Active 133-MHz, 48-MHz PLL Inactive
1	1	1	Active 133-MHz, 48-MHz PLL Active

Table 3. Truth Table

SEL 133/100#	SEL1	SEL0	CPU	CPUdiv2	3V66	PCI	48MHz	REF	IOAPIC	Notes
0	0	0	HI-Z	HI-Z	HI-Z	HI-Z	HI-Z	HI-Z	HI-Z	2
0	0	1	n/a	n/a	n/a	n/a	n/a	n/a	n/a	
0	1	0	100 MHz	50 MHz	66 MHz	33 MHz	HI-Z	14.318 MHz	16.67 MHz	3
0	1	1	100 MHz	50 MHz	66 MHz	33 MHz	48 MHz	14.318 MHz	16.67 MHz	4, 7, 8
1	0	0	TCLK/2	TCLK/4	TCLK/4	TCLK/8	TCLK/2	TCLK	TCLK16	5, 6
1	0	1	n/a	n/a	n/a	n/a	n/a	n/a	n/a	
1	1	0	133 MHz	66 MHz	66 MHz	33 MHz	HI-Z	14.318 MHz	16.67 MHz	3
1	1	1	133 MHz	66 MHz	66 MHz	33 MHz	48 MHz	14.318 MHz	16.67 MHz	4, 7, 8

**Table 4. Maximum Supply Current** 

Condition	Max. 2.5V supply consumption Max. discrete cap loads, V <sub>DDQ2</sub> =2.625V All static inputs=V <sub>DDQ3</sub> or GND	Max. 3.3V supply consumption Max. discrete cap loads, V <sub>DDQ3</sub> =3.465V or GND
Powerdown Mode (PWRDWN#=0)	100 μΑ	200 μΑ
Full Active 100 MHz SEL133/100#=0 SEL1, 0=11 CPU_STOP#, PCI_STOP#=1	75 mA	160 mA
Full Active 133 MHz SEL133/100#=0 SEL1, 0=11 CPU_STOP#, PCI_STOP#=1	90 mA	160 mA

#### Notes:

- Provided for board level "bed of nails" testing.

  48-MHz PLL disabled to reduce component jitter.

  Normal" mode of operation.

  TCLK is a test clock over driven on the X1 input during test mode. TCLK mode is based on 133-MHz CPU select logic.

  Required for DC output impedance verification.

  Range of reference frequency is min.=14.316, nominal = 14.31818 MHz, max.=14.32 MHz.

  Frequency accuracy of 48 MHz is +167 PPM to match USB default.



Table 5. Clock Enable Configuration<sup>[9, 10, 11, 12, 13, 14]</sup>

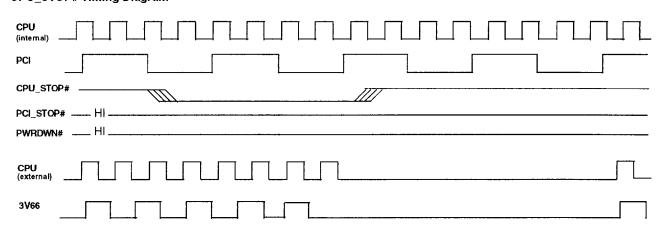
CPU_STOP#	PWRDWN#	PCI_STOP#	CPU	CPUdiv2	IOAPIC	3V66	PCI	PCI_F	REF, 48MHz	osc.	VCOs
Х	0	Х	LOW	LOW	LOW	LOW	LOW	LOW	LOW	OFF	OFF
0	1	0	LOW	ON	ON	LOW	LOW	ON	ON	ON	ON
0	1	1	LOW	ON	ON	LOW	ON	ON	ON	ON	ON
1	1	0	ON	ON	ON	ON	LOW	ON	ON	ON	ON
1	1	1	ON	ON	ON	ON	ON	ON	ON	ON	ON

Table 6. Power Management State Transition<sup>[15, 16]</sup>

		Latency
Signal	Signal State	No. of rising edges of PCI Clock
CPU_STOP#	0 (disabled)	1
	1 (enabled)	1
PCI_STOP#	0 (disabled)	1
	1 (enabled)	1
PWRDWN#	1 (normal operation)	3 ms
	0 (power down)	2 max.

#### **Timing Diagrams**

CPU\_STOP# Timing Diagram<sup>[17, 18, 19, 20, 21, 22]</sup>



#### Notes:

- LOW means outputs held static LOW as per latency requirement below.

- LOW means outputs held static LOW as per latency requirement below.

  ON means active.

  PWRDWN# pulled LOW, impacts all outputs including REF and 48-MHz outputs.

  All 3V66 as well as all CPU clocks stop cleanly when CPU\_STOP# is pulled LOW.

  CPUdiv2, IOAPIC, REF, 48MHz signals are not controlled by the CPU\_STOP# functionality and are enabled in all conditions except PWRDWN#=LOW.

  An "X" indicates a "don't care" condition.

  Clock on/off latency is defined in the number of rising edges of the free-running PCI clock between when the clock disable goes LOW/HIGH to when the first valid clock comes out of the device.

  Power up latency is from when PWRDWN# goes inactive (HIGH) to when the first valid clocks are driven from the device.

  All internal timing is referenced to the CPU clock.

  The internal label means inside the chip and is a reference only. This, in fact, may not be the way that the control is designed.

  CPU\_STOP# signal is an input signal that must be made synchronous to free-running PCI\_E.

  3V66 clocks also stop/start before.

  PWRDWN# and PCI\_STOP# are shown in a HIGH state.

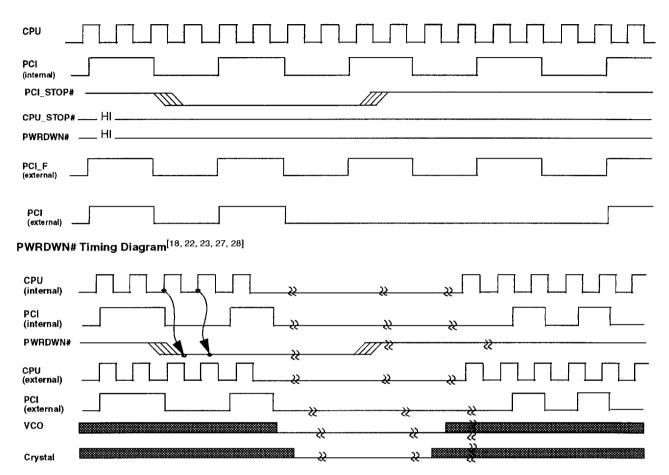
  Diagrams shown with respect to 133 MHz. Similar operation when CPU clock is 100 MHz.

- Diagrams shown with respect to 133 MHz. Similar operation when CPU clock is 100 MHz.



# Timing Diagrams (continued)

PCI\_STOP# Timing Diagram[18, 22, 23, 24, 25, 26]



- All internal timing is referenced to the CPU clock.
  PCI\_STOP# signal is an input signal that must be made synchronous to PCI\_F output.
  All other clocks continue to run undisturbed.
  PWRDWN# and CPU\_STOP# are shown in a HIGH state.
  PWRDWN is an asynchronous input and metastable conditions could exist. This signal must be synchronized.
  The shaded Sections on the VCO and the Crystal signals indicate an active clock.



# **Absolute Maximum Ratings**

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V <sub>DD</sub> , V <sub>IN</sub>	Voltage on any pin with respect to GND	-0.5 to +7.0	V
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
T <sub>A</sub>	Operating Temperature	0 to +70	°C
T <sub>B</sub>	Ambient Temperature under Bias	-55 to +125	°C
ESD <sub>PROT</sub>	Input ESD Protection	2 (min.)	kV

# DC Electrical Characteristics: $T_A = 0$ °C to +70°C, $V_{DDQ3} = 3.3V \pm 5\%$ , $V_{DDQ2} = 2.5V \pm 5\%$

Parameter	Description	Test Condition	Min.	Тур.	Max.	Unit
Supply Curr	ent	,	1			·
I <sub>DD-3.3V</sub>	Combined 3.3V Supply Current	CPU0:3 =133 MHz <sup>[29]</sup>			160	mA
I <sub>DD-2.5</sub>	Combined 2.5V Supply Current	CPU0:3 =133 MHz <sup>[29]</sup>			90	mA
Logic Inputs	s (All referenced to V <sub>DDQ3</sub> = 3.3V)	·····	•	•	•	
V <sub>IL</sub>	Input Low Voltage		GND -0.3		0.8	٧
V <sub>IH</sub>	Input High Voltage		2.0		VDD+ 0.3	٧
I <sub>IL</sub>	Input Low Current <sup>[30]</sup>				-25	μA
I <sub>IH</sub>	Input High Current <sup>[30]</sup>				10	μA
I <sub>IL</sub>	Input Low Current, SEL133/100# <sup>[30]</sup>				<b>-</b> 5	μΑ
I <sub>IH</sub>	Input High Current, SEL133/100#[30]				5	μΑ
Clock Outpu	its					
CPU, CPUdi	v2, IOAPIC (Referenced to V <sub>DDQ2</sub> )	Test Condition	Min.	Тур.	Max.	Unit
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 1 mA			50	mV
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -1 mA	2.2			٧
l <sub>OL</sub>	Output Low Current	V <sub>OL</sub> = 1.25V	45	65	100	mA
l <sub>он</sub>	Output High Current	V <sub>OH</sub> = 1.25V	45	65	100	mA
48MHz, REF	(Referenced to V <sub>DDQ3</sub> )	Test Condition	Min.	Тур.	Max.	Unit
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 1 mA			50	mV
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -1 mA	3.1			٧
l <sub>OL</sub>	Output Low Current	V <sub>OL</sub> = 1.5V	45	65	100	mA
loн	Output High Current	V <sub>OH</sub> = 1.5V	45	65	100	mA
PCI, 3V66 (F	leferenced to V <sub>DDQ3</sub> )	Test Condition	Min.	Тур.	Max.	Unit
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 1 mA			50	mV
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -1 mA	3.1			٧
l <sub>OL</sub>	Output Low Current	V <sub>OL</sub> = 1.5V	70	100	145	mA
I <sub>ОН</sub>	Output High Current	V <sub>OH</sub> = 1.5V	65	95	135	mA

<sup>29.</sup> All clock outputs loaded with 6"  $60\Omega$  transmission lines with 20-pF capacitors. 30. W158 logic inputs have internal pull-up devices, except SEL133/100# (pull-ups not CMOS level).



# DC Electrical Characteristics: $T_A = 0$ °C to +70°C, $V_{DDQ3} = 3.3V\pm5\%$ , $V_{DDQ2} = 2.5V\pm5\%$

Parameter	Description	Test Condition	Min.	Тур.	Max.	Unit
Crystal Osc	illator	· · · · · · · · · · · · · · · · · · ·		•	•	•
V <sub>TH</sub>	X1 Input threshold Voltage <sup>[31]</sup>			1.65		V
C <sub>LOAD</sub>	Load Capacitance, Imposed on External Crystal <sup>[32]</sup>			18		pF
C <sub>IN,X1</sub>	X1 Input Capacitance <sup>[33]</sup>	Pin X2 unconnected		28		pF
Pin Capacita	ance/Inductance					
C <sub>IN</sub>	Input Pin Capacitance	Except X1 and X2			5	pF
Соит	Output Pin Capacitance				6	pF
L <sub>IN</sub>	Input Pin Inductance				7	nH

#### 3.3V AC Electrical Characteristics

 $\rm T_A$  = 0°C to +70°C,  $\rm V_{DDQ3}$  = 3.3V±5%,  $\rm V_{DDQ2}$  = 2.5V± 5%,  $\rm f_{XTL}$  = 14.31818 MHz Spread Spectrum function turned off

AC clock parameters are tested and guaranteed over stated operating conditions using the stated lump capacitive load at the clock output.<sup>[34]</sup>

#### 3V66 Clock Outputs, 3V66\_0:3 (Lump Capacitance Test Load = 30 pF)

Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency	Note 35		66.6		MHz
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	1		4	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	1		4	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		15		Ω

X1 input threshold voltage (typical) is V<sub>DD</sub>/2.
 The W158 contains an internal crystal load capacitor between pin X1 and ground and another between pin X2 and ground. Total load placed on crystal is 18 pF; this includes typical stray capacitance of short PCB traces to crystal.
 X1 input capacitance is applicable when driving X1 with an external clock source (X2 is left unconnected).
 Period, jitter, offset, and skew measured on rising edge at 1.5V.
 3V66 is CPU/2 for CPU = 133 MHz and (2 x CPU)/3 for CPU = 100 MHz.



#### PCI Clock Outputs, PCI\_F and PCI1:7 (Lump Capacitance Test Load = 30 pF)

Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
t <sub>P</sub>	Period	Measured on rising edge at 1.5V <sup>[36]</sup>	30			ns
tн	High Time	Duration of clock cycle above 2.4V	12			ns
t <sub>L</sub>	Low Time	Duration of clock cycle below 0.4V	12			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	1		4	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	1		4	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
tic	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.5V. Maximum difference of cycle time between two adjacent cycles.			500	ps
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.5V			500	ps
to	3V66 to PCI Clock Skew	Covers all 3V66/PCI outputs. Measured on rising edge at 1.5V. 3V66 leads PCI output.	1.5		3	ns
tq	CPU to PCI Clock Skew	Covers all CPU/PCI outputs. Measured on rising edge at 1.5V. CPU leads PCI output.	1.5		4	ns
fsт	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		15		Ω

### REF Clock Outputs, REF0:1 (Lump Capacitance Test Load = 20 pF)

Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Frequency generated by crystal oscillator		14.318		MHz
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	0.5		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	0.5		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.	,		3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		25		Ω

#### 48-MHZ Clock Output (Lump Capacitance Test Load = 20 pF)

Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Determined by PLL divider ratio (see m/n below)		48.008		MHz
f <sub>D</sub>	Deviation from 48 MHz	(48.008 – 48)/48		+167		ppm
m/n	PLL Ratio	(14.31818 MHz x 57/17 = 48.008 MHz)		57/17		
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	0.5		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	0.5		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		25		Ω

Note:

36. PCI clock is CPU/4 for CPU = 133 MHz and CPU/3 for CPU = 100 MHz.



# 2.5V AC Electrical Characteristics

 $T_A$  = 0°C to +70°C,  $V_{DDQ3}$  = 3.3V±5%,  $V_{DDQ2}$ = 2.5V±5%  $f_{XTL}$  = 14.31818 MHz Spread Spectrum function turned off

AC clock parameters are tested and guaranteed over stated operating conditions using the stated lump capacitive load at the clock output.[37]

#### CPU Clock Outputs, CPU0:3 (Lump Capacitance Test Load = 20 pF)

			CPU	= 133	MHz	CPU				
Parameter	Description	Test Condition/Comments	Min. Typ. N		Max.	Min.	Тур. Мах		. Unit	
tp	Period	Measured on rising edge at 1.25V	7.5		7.65	10		10.2	ns	
t <sub>H</sub>	High Time	Duration of clock cycle above 2.0V	1.87			3.0			ns	
tլ	Low Time	Duration of clock cycle below 0.4V	1.67			2.8			ns	
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0V	1		4	1		4	V/ns	
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	1		4	1		4	V/ns	
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	45		55	%	
tic	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Maximum difference of cycle time between two adjacent cycles.			150			150	ps	
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.25V			175			175	ps	
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3			3	ms	
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.			20		Ω			

#### CPUdiv2 Clock Outputs, CPUdiv2\_0:1 (Lump Capacitance Test Load = 20 pF)

			CPU	= 133	MHz	CPU			
Parameter	Description	Test Condition/Comments	Min. Typ. Ma		Max.	Min.	Тур.	Max.	Unit
tp	Period	Measured on rising edge at 1.25V	15		15.3	20		20.4	ns
t <sub>H</sub>	High Time	Duration of clock cycle above 2.0V	5.25			7.5			ns
tL	Low Time	Duration of clock cycle below 0.4V	5.05			7.3			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0V	1		4	1		4	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	1		4	1		4	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	45		55	%
tic	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Maximum difference of cycle time between two adjacent cycles.			250			250	ps
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.25V			175			175	ps
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		20		Ω			

Note:

<sup>37.</sup> Period, Jitter, offset, and skew measured on rising edge at 1.25V.



# IOAPIC Clock Outputs, IOAPIC0:2 (Lump Capacitance Test Load = 20 pF)

Parameter	meter Description Test Condition/Comments		Min	Тур	Max	Unit
f	Frequency	Note 38		16.67		MHz
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0V	1		4	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	1		4	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	%
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		20		Ω

Note:

38. IOAPIC clock is CPU/8 for CPU = 133 MHz and CPU/6 for CPU = 100 MHz.

# Ordering Information

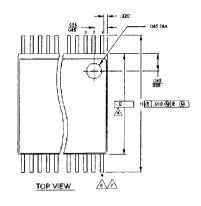
Ordering Code	Package Name	Package Type
W158	Н	56-pin SSOP (300 mils)

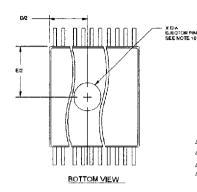
Document #: 38-00819



#### Package Diagram

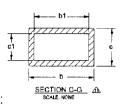
#### 56-Pin Small Shrink Outline Package (SSOP, 300 mils)





SEE DETAIL A

END VIEW



# NOTES:

- MAXIMUM DIE THICKNESS ALLOWABLE IS 025

- AMAMMUM DIE THICKNESS ALLOWABLE IS 025

  DIMENSIONING & TOLERANCING PER ANSI

  Y14 \$M 1882.

  ↑ 'T' & A' REFERENCE DATUM.

  ↑ 'T' & A' REFERENCE DATUM.

  ↑ 'T' & A' REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, BUT DOES INCLUDE MOLD PLASH OR PROTRUSIONS SHALL NOT EXCEED DOS INCHES PER SIDE.

  ↑ 'T' IS THE LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE

  ↑ 'N' IS THE NUMBER OF TERMINAL POSITIONS.

  ↑ TERMINAL POSITIONS ARE SHOWN FOR REFERENCE ONLY.

- S. 'N' IS THE NUMBER OF TERMINAL POSITIONS.

  ☐ TERMINAL POSITIONS ARE SHOWN FOR REFERENCE ONLY.

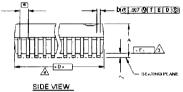
  S. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN 003 INCHES AT SEATING PLANE.

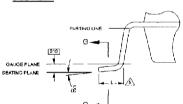
  ☐ COUNTROLLING DIMENSION: INCHES.

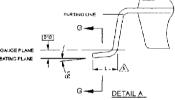
  ☐ COUNTRY OF ORIGIN LOCATION AND EJECTOR PIN ON PACKAGE BOTTOM IS OPTIONAL AND DEPENDS ON ASSEMBLY LOCATION.

  ☐ THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 INCHES AND .010 INCHES FROM THE LEAD BETWEEN .005 INCHES AND .010 INCHES FROM THE LEAD THES.

  12. THIS PART IS COMPILIANT WITH JEDEC SPECIFICATION MO-118, VARIATIONS AA. AB. EXCEPT CHAMFER DIMENSION IN JEDEC SPECIFICATION FOR IN IS. 0157.025\*.







#### Summary of nominal dimensions in inches:

Body Width: 0.296 Lead Pitch: 0.025 Body Length: 0.625 Body Height: 0.102

5	COMMON				NOTE		4		6		
1 4	DIMENSIONS F		DIMENSIONS			N <sub>a</sub>	VARI-		D		T N
L 3	MIN.	NOM.	MAX.	۱.'.	ATIONS	MIN.	NOM.	MAX.			
[A]	.095	.102	.110	T	AA	.620	.625	.630	48		
[Ai	.008	.012	.016		AB	.720	.725	.730	56		
A,	.088	090	.092								
i b i	.008	.010	.0135			T1 110	TIBLE				
ъ.	.008	.010	.012			THIS	TABLE II	N INCH	ES		
C	.005	-	.010		1						
C,	.005	.006	.0085								
D		VARIATION		4							
E	.292	.296	.299								
e		025 BSC									
H	.400	.406	.410								
_h;	.010	.013	.016								
	.024	.032	.040								
N	SEE	VARIATION	IS	6							
X	.085	.093	.100	10							
œ	а	5°	8°		1						

2	COMMON				NOTE		4		161
1,4				٠,	VARI-	Ď.			Ň
0	MIN.	NOM.	MAX.	1	ATIONS	MIN.	NOM.	MAX.	
Α	2.41	2.59	2.79		AA	15.75	15,88	16.00	48
A,	0.20	0.31	0.41		AB	18.29	18.42	18.54	56
A,	2.24	2.29	2.34						
ь	0.203	0.254	0.343			T. 110 TA	St E 181 8		
b.	0.203	0.254	0.305			THIS TAI	SLEININ	HLLIME	EK2
C	0.127	-	0.254						
C	0.127	0.152	0.216						
D	SEE	VARIATION		4					
	7.42	7.52	7.59						
e		0.635 BSC							
$\square$ H	10.16	10.31	10.41						
h	0.25	0.33	0.41						
	0.61	0.81	1.02						
N	SEE VARIATIONS			6					
X	2.16	2.36	2.54	10					
ď	0°	5°	8°						

<sup>©</sup> Cypress Semiconductor Corporation, 1999. The information contained herein is subject to change without notice. Cypress Semiconductor Corporation assumes no responsibility for the use of any circuitry other than circuitry embodied in a Cypress Semiconductor product. Nor does it convey or imply any license under patent or other rights. Cypress Semiconductor does not authorize its products for use as critical components in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of Cypress Semiconductor products in life-support systems application implies that the manufacturer assumes all risk of such use and in doing so indemnifies Cypress Semiconductor against all charges.